VBT4060C-M3, VBT4060CHM3

Vishay General Semiconductor

# **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.32$  V at  $I_F = 5.0$  A



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PRIMARY CHARACTERISTICS					
Package	TO-263AB				
I <sub>F(AV)</sub>	2 x 20 A				
V <sub>RRM</sub>	60 V				
I <sub>FSM</sub>	240 A				
$V_F$ at $I_F = 20$ A	0.48 V				
T <sub>J</sub> max.	150 °C				
Diode variations	Common cathode				

### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- AEC-Q101 qualified available
  Automotive ordering code: base P/NHM3
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

#### Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test **Polarity:** As marked

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT4060C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current	per device		40	А	
(fig. 1)	per diode	I <sub>F(AV)</sub>	20	A .	
Peak forward surge current 8.3 ms single half sine-wa on rated load	I <sub>FSM</sub>	240	А		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MIN.	UNIT	
Instantaneous forward voltage per diode <sup>(1)</sup>	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 25 °C	VF	0.43	-	V	
	I <sub>F</sub> = 10 A			0.48	-		
	I <sub>F</sub> = 20 A			0.53	0.62		
	I <sub>F</sub> = 5.0 A	T <sub>A</sub> = 125 °C		0.32	-		
	I <sub>F</sub> = 10 A			0.39	-		
	I <sub>F</sub> = 20 A			0.48	0.57		
Reverse current per diode <sup>(2)</sup>	V <sub>B</sub> = 60 V	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	- I <sub>R</sub>	-	6.0	mA	
	$v_{\rm R} = 00 v$			34	190		

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

Revision: 03-Jan-17

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RoHS

COMPLIANT HALOGEN



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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VBT4060C	UNIT	
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	1.5	°C/W	
	per device		0.8	0/11	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VBT4060C-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VBT4060C-M3/8W	1.39	8W	800/reel	Tape and reel	
TO-263AB	VBT4060CHM3/I (1)	1.38	I	800/reel	Tape and reel	

Note

(1) AEC-Q101 qualified

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

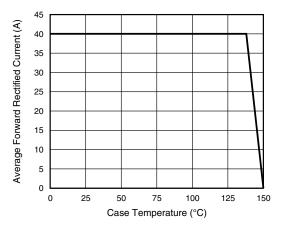


Fig. 1 - Maximum Forward Current Derating Curve

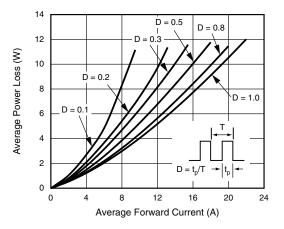


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

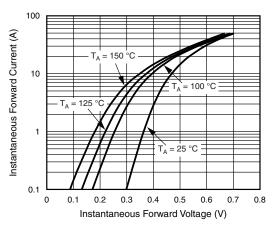
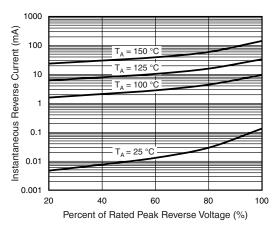
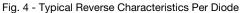


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode





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## 10 000 T<sub>J</sub> = 25 °C f = 1.0 MHz $V_{sig} = 50 \text{ mV}_{p-p}$ Junction Capacitance (pF) 1000 100 10 100 0.1 1 Reverse Voltage (V)

Fig. 5 - Typical Junction Capacitance Per Diode

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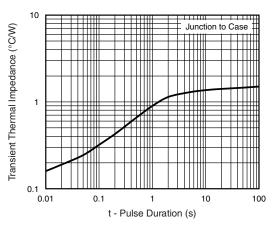
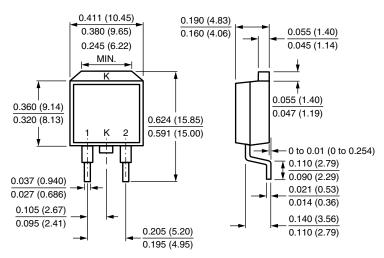


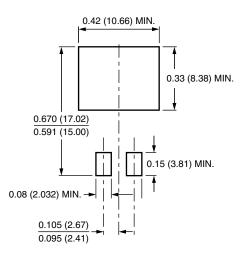
Fig. 6 - Typical Transient Thermal Impedance Per Diode

# **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



## **TO-263AB**

## Mounting Pad Layout





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